

- Low current consumption, CMOS TCXO
- Quick turnaround, low-cost TCXO
- Standard 5.0 x 7.0mm, 6 pad SMD package
- Supply voltage 2.5V or 3.3 VDC
- Member of the QuikXO family of products



### DESCRIPTION

EMQN576T series TCXOs are packaged in a standard, 7.0 x 5.0mm outline, SMD package. With squarewave (CMOS) output, tolerance is from  $\pm 1.0$ ppm over  $-40^\circ$  to  $+85^\circ\text{C}$ . The part has low supply current, 24mA typical at 50MHz.

### SPECIFICATION

Product Series Code	TCXO: EMQN576T VCTCXO: VEMQN576T
Frequency Range:	10.0MHz to 245MHz
Supply Voltage:	+2.5VDC $\pm 5\%$ or +3.3Volts $\pm 5\%$
Output Logic Levels:	Logic High: 90% Vdd min. Logic Low: 10% Vdd max.
Output Waveform:	Squarewave, LVCMOS
Phase jitter rms (12kHz to 20MHz):	0.8ps typical
Initial Calibration Tolerance:	$\pm 2.0$ ppm at $+25^\circ \pm 2^\circ\text{C}$
Frequency Stability	
vs. Temperature:	
-30° to +85°C:	$\pm 2.0$ ppm standard $\pm 1.0$ ppm available
-40 to +85°C:	$\pm 2.5$ ppm standard $\pm 1.0$ ppm available
vs. Ageing:	$\pm 1.0$ ppm max. per year $25^\circ\text{C}$
vs. Voltage Change:	$\pm 0.2$ ppm max. $\pm 5\%$ change
vs. Load Change:	$\pm 0.2$ ppm max. $\pm 10\%$ change
vs. Reflow (SMD type):	$\pm 1.0$ ppm max. for one reflow and measured after 24 hours.
Rise/Fall Times:	1.5ns typ. 10% to 90% wavef.
Duty Cycle:	50% $\pm 5\%$ standard,
Start-up Time:	5ms typical, 10ms max.
Output Load:	15pF
Current Consumption Vdd +2.5V	
at 50MHz:	24mA typical
at 125MHz:	28mA typical
at 200MHz:	30mA typical
Current Consumption Vdd +3.3V	
at 50MHz:	26mA typical
at 125MHz:	30mA typical
at 200MHz:	34mA typical
Current with output disabled:	18mA typical
Start-up Time:	5ms max.
Phase Jitter rms (12kHz to 20MHz):	0.8ps typ., 1.0ps max.
Phase Jitter rms (1.875MHz to 20MHz):	200fs max.

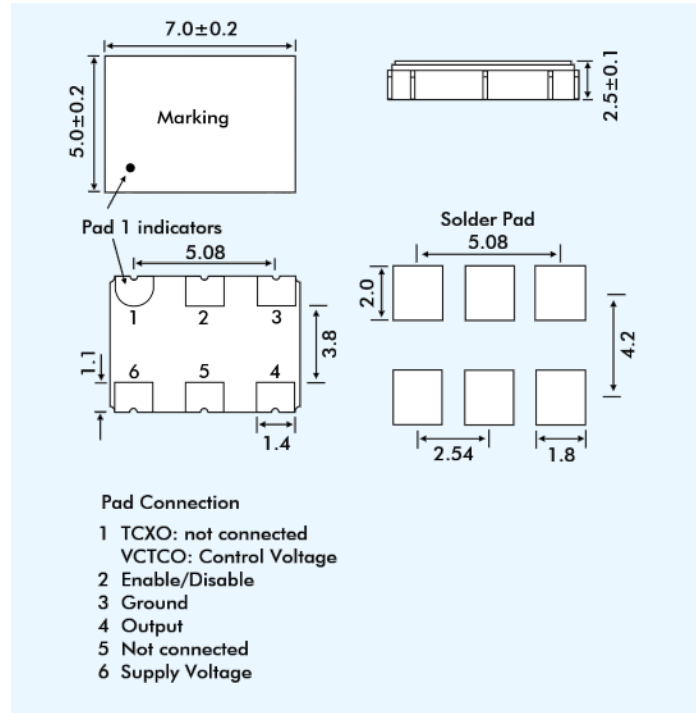
### PART NUMBERS

Example:

**EMQN576T33-50.000-2.5/-30+85**

- Series Description  
TCXO = EMQN576T  
VCTCXO = VEMQN576T
- Supply Voltage Code  
3.3V = 33  
2.5V = 25
- Frequency (MHz)
- Stability over OTR ( $\pm$ ppm)
- Operating Temperature Range (OTR) ( $^\circ\text{C}$ )  
(Lower and upper limits.)

### EMQN576T - OUTLINES AND DIMENSIONS



### VEMQN576T VOLTAGE CONTROL SPECIFICATION

Control Voltage Centre & Range:	+1.5V $\pm 1.0$ V for both +2.5V and 3.3V supplies
Frequency Pulling Range:	$\pm 8$ ppm min.
Slope Polarity:	Positive (increase of control voltage increases output freq.)
Linearity:	$\pm 1\%$ typical $\pm 10\%$ max.
Input Impedance:	770k $\Omega$ typical
Harmonics:	-5.0dBc max.

### SSB PHASE NOISE and PHASE JITTER DATA

(Typical VDD = +3.3V, V Control = 0.0V) dBc/Hz

Frequency	96MHz	192MHz
10Hz Offset	-71	-56
100Hz	-96	-91
1kHz	-114	-108
10kHz	-124	-119
100kHz	-127	-122
1MHz	-134	-128
5MHz	-153	-151
10MHz	-154	-153
20MHz	-156	-152
Phase Jitter ps 12kHz - 20MHz rms	0.85	0.77

### OUTPUT ENABLE FUNCTION

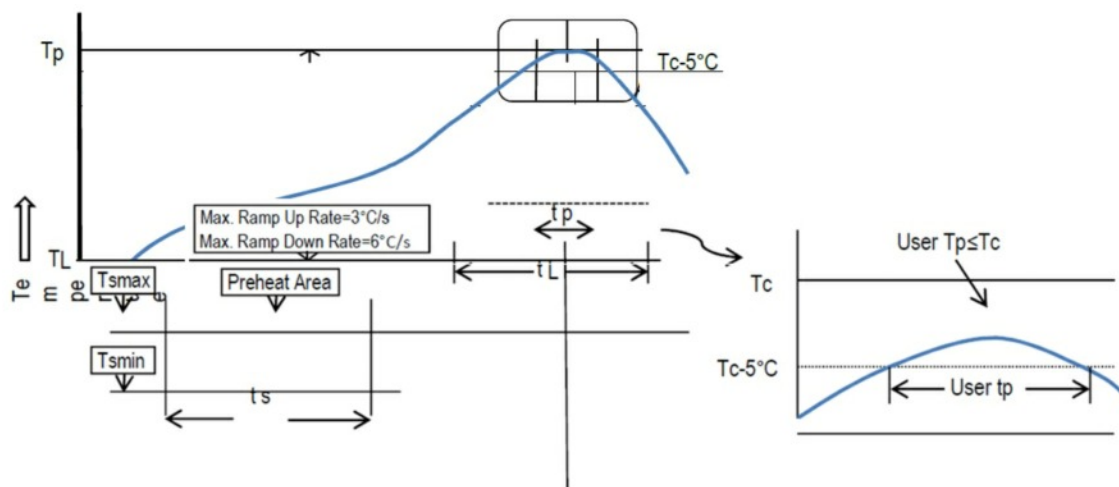
OE Control	Enable:	0.9% Vdd minimum or no connection to enable output
	Disable:	0.1%Vdd maximum to disable output (high impedance)
Output Enable Time:		200ns max.
Output Disable Time:		50ns max.

### ENVIRONMENTAL PERFORMANCE SPECIFICATIONS

Status:	RoHS Compliant, Pb (lead) free in accordance with EU Directive 2002/95/EC 6/6(2002/95/EC) and WEEE (2002/96/EC)
Moisture Sensitivity:	Level 1 (infinite) according to IPC/JEDEC J-STD-020D.1
Second Level Interconnect:	e4
Storage Temperature Range:	-55° to +125°C
Humidity:	85%RH, 85°C, 48 hours
Fine Leak / Gross Leak:	MIL-STD-202F method 1014, condition A / MIL-STD-883, method 1014, condition C
Solderability:	MIL-STD-202F method 208E
Reflow:	260°C for 10s, x2
Vibration:	MIL-STD-202F method 204, 35g, 50 to 2000Hz
Shock:	MIL-STD-202F method 2133B, test condition E, 1000g <sup>2</sup> 1/2 sinewave
Resistant to Solvents:	MIL-STD-202F method 215
Temperature Cycling:	MIL-STD-883 method 1010
ESD Rating:	Human Body Model (HBM): 1500V min.
Pad Surface Finish:	Gold (Au) 0.3µm to 1.0µm over nickel (N) 1.27µm to 8.89µm
Weight of device:	0.045gm typical

### RECOMMENDED SOLDER REFLOW PROFILE

Per IPC/JEDEC J-STD-020D.1



Profile Feature	SN-Pb Eutectic Assembly	PB-Free Assembly
Preheat/Soak - Temperature min. ( $T_s$ min.) - Temperature max. ( $T_s$ max.) - Time ( $T_s$ ( $T_s$ min. to $T_z$ max.))	100°C 150°C 60 to 120 seconds	150° 200° 60 to 120 seconds
Ramp-up Rate ( $T_L$ to $T_p$ )	3°C/sec. max.	3°C/sec. max.
Liquidous Temperature ( $T_L$ ) Time ( $T_L$ ) maintained above $T_L$	183°C 60 to 150 seconds	217°C 60 to 150 seconds
Peak package body temperature ( $T_p$ )	235°C	260°C
Time ( $T_p$ ) within $5^{\circ}C$ of the classification temperature $T_c$	10 to 30 seconds	20 to 40 seconds
Ramp-down rate ( $T_p$ to $T_L$ )	6°/second max.	6°/second max.
Time $25^{\circ}C$ to peak temperature	6 minutes max.	8 minutes max.

All temperatures refer to topside of the package, measured on the package body surface.